

Monoclinic LaSb₂ Superconducting Thin Films

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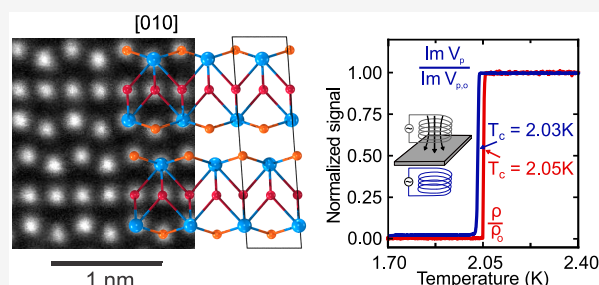
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Supporting Information

ABSTRACT: Rare-earth diantimonides exhibit coupling between structural and electronic orders, which are tunable under pressure and temperature. Here we present the discovery of a new polymorph of LaSb₂ stabilized in thin films synthesized using molecular beam epitaxy. Using diffraction, electron microscopy, and first-principles calculations we identify a YbSb₂-type monoclinic lattice as a yet-uncharacterized stacking configuration. The material hosts superconductivity with a $T_c = 2$ K, which is enhanced relative to the bulk ambient phase, and a long superconducting coherence length of 1730 Å. This result highlights the potential thin film growth has in stabilizing novel stacking configurations in quasi-two-dimensional compounds with competing layered structures.

KEYWORDS: thin-film growth, superconductivity, two-dimensional materials, rare-earth antimonide



Layered intermetallics featuring the square-net structural motif form a versatile platform^{1–4} for engineering electronic phases through chemical control over lattice symmetries^{5–7} and stacking configurations.⁸ Using common experimental tuning knobs such as chemical substitution, pressure (P) and temperature (T), it is known that structural configurations compete and can be modified with a subsequent influence on the flavor of the electronic ground state of the compound.^{9–15} Antimony-based $LnSb_2$ (Ln = lanthanide element) materials form stoichiometric crystals, and refined structural analysis¹⁶ describes the unit cell as being formed by two quintuple layer (QL) blocks, each consisting of two Ln-Sb corrugated layers sandwiching a two-dimensional Sb square net sheet. Variations in electron count on the square net Sb sites as determined by the rare-earth ionization state leads to a variety of bonding and stacking arrangements.¹⁷ In the case of EuSb₂, the Eu²⁺ valence state causes a distortion of the Sb square net into zigzag chains and a monoclinic crystal structure,^{18,19} while the orthorhombic structure of YbSb₂ is stabilized²⁰ by a small admixture of Yb³⁺ ions within a predominantly 2+ network.²¹ Finally, in the case of (La, Ce, Nd, Sm)Sb₂ compounds, the 3+ valence again gives rise to an orthorhombic crystal in the so-called SmSb₂ structure type.^{16,22} This latter structure differs from the YbSb₂ in the stacking arrangement of QL along the c -axis direction, which can be conceptualized by a displacement vector \vec{d} within the a – b plane, as illustrated in Figure 1a.

LaSb₂ stands out as a particularly sensitive structure that is susceptible to electronic and structural instabilities when tuning T and P . Bulk crystals grown with the self-flux method²³ form large, micaceous crystals with high residual resistivity ratios (RRR)^{22,24} and nonsaturating positive magnetoresist-

ance (MR).^{22,25} Pronounced hysteretic electrical resistance when sweeping T is resolved under ambient P conditions.^{15,26–28} Under application of moderate P , the hysteretic feature is suppressed to low T and is completely absent by $P \approx 12$ kbar. Accompanying this suppression is a sharpening of the superconducting (SC) transition under P and an increase in SC critical temperature (T_c) to a maximum of $T_c \approx 2$ K.^{15,29,30} However, due to the micacity of crystals, reliable structural analysis at high P remains challenging and therefore complicates a full understanding of correlation between structural and electronic properties.

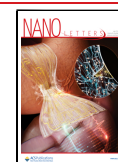
Molecular-beam epitaxy (MBE) as a synthesis technique has found much application in the engineering of low-temperature electronic ground states primarily through dimensional confinement^{31–34} and epitaxial strain.^{35–37} We use this technique to synthesize and study LaSb₂ thin films on MgO (001) (space group $Fm\bar{3}m$, $a = 4.21$ Å). Despite the lattice constants being relaxed in the (001)-oriented films, we discover a not previously observed crystal structure derived from the YbSb₂ structure type with an additional monoclinic shear. First-principles calculations suggest this layering arrangement as the lowest energy state, even compared to the observed SmSb₂ structure type of LaSb₂ single crystals

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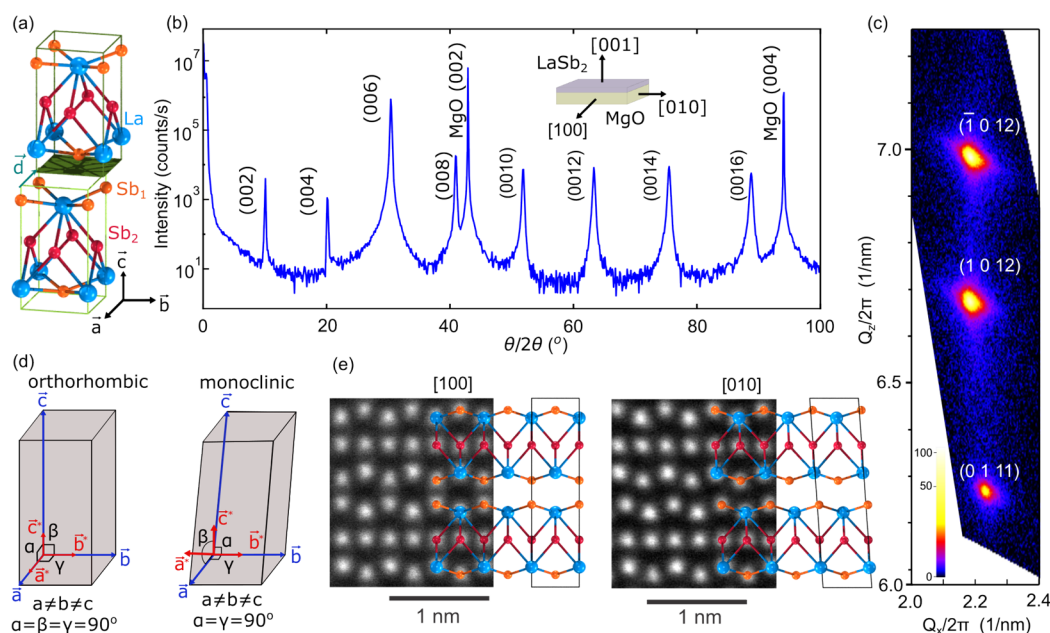


Figure 1. (a) Two QL building blocks of LaSb_2 , where the upper QL block is shifted relative to the lower one by lateral displacement. (b) $\theta/2\theta$ diffraction pattern from LaSb_2 . (c) Reciprocal space map taken along the $h = 1$ rod. Splitting at finite Q_x indicates a monoclinic tilt. (d) Schematic unit cells of the orthorhombic and monoclinic crystal systems. (e) Atomic arrangements obtained in transmission electron microscopy within domains with an overlay of the calculated unit cell modified with experimental lattice constant values.

commonly observed in bulk crystals. The electronic structure is characterized as a multiband system with one hole-like band derived from the La–Sb corrugated layer and multiple electron-like bands from the Sb sheet. The films display no resistance anomaly at high T indicative of a structural phase transition and are superconducting with a $T_c = 2.03$ K, which is enhanced relative to the bulk ambient where $T_c \approx 1$ K. The ability to stabilize stacking configurations of quasi-2D materials not observed in their bulk counterparts emphasizes the extra degrees of freedom available to thin film synthesis of this broad class of materials.

The structure of LnSb_2 materials is composed of QL blocks, which can form a variety of stacking configurations depending on their relative displacement.^{16,20} This is depicted in Figure 1a with the vector \vec{d} , which represents the displacement in the a – b plane. Each QL contains one rare earth site, in this case La (blue), and two different Sb sites, noted as Sb_1 (orange) and Sb_2 (red) in Figure 1a. Out-of-plane X-ray diffraction of films presented in Figure 1b shows a single-phase, c -axis oriented film with a lattice parameter of $c = 17.62$ Å. This value is compressed relative to the value found in bulk LaSb_2 in the SmSb_2 structure where $c = 18.56$ Å.¹⁶ A film of thickness $t = 144$ nm was used for determination of the lattice parameters. Rocking curve analysis reveals a full-width-half maximum of 0.03° , indicating low mosaicity, and a φ -scan using the $(0\ 1\ 9)$ reflection reveals a $[100]_{\text{LaSb}_2} \parallel [100]_{\text{MgO}}$ epitaxial relationship with additional domains oriented $[100]_{\text{LaSb}_2} \parallel [110]_{\text{MgO}}$ (Figure S2).

Asymmetric reciprocal space mapping (RSM) (Figure 1c) along the $h = 1$ truncation rod was used to determine the in-plane lattice constants. The data reveal a twinned crystal structure with sets of spots corresponding to values from the two different crystal axes. For reflections corresponding to the a -axis, a pair of spots $((1\ 0\ 12)$ and $(\bar{1}\ 0\ 12))$ are observed, whereas intensity at $(0\ 1\ 11)$ is associated with diffraction from

the b -axis. To simplify comparison with similar, bulk crystal polymorphs, we adopt a setting where the c -axis is taken to be the long axis. The corresponding a - and b -axis lattice constants were found to be $a = 4.52$ Å and $b = 4.43$ Å. The similarity of the lattice constant values for the grown film ($\frac{a-b}{a} \approx 2\%$) and their $\approx 6\%$ mismatch with the cubic MgO substrate result in a relaxed film with twinned domains wherein both a - and b -axes predominantly align with the $\langle 100 \rangle$ directions of the substrate. For comparison, the bulk ambient phase adopts the SmSb_2 structure (space group No. 64 $Cmca$) with $a = b = 4.42$ Å, $\gamma = 91.27^\circ$.

The distribution of the $(1\ 0\ 12)$ and $(\bar{1}\ 0\ 12)$ spots along \vec{Q}_z reveals a monoclinic structure for the crystal, which can be understood by referring to Figure 1d. When a crystal distorts from orthorhombic to monoclinic, the a^* reciprocal lattice vector forms a finite angle with \vec{a} so as to maintain orthogonality with \vec{c} . The reduced symmetry of the monoclinic structure relative to the MgO substrate leads to domains oriented 180° with respect to each other and the appearance of both $(h0l)$ and $(-h0l)$ reflections along the same direction. Thus, a single spot corresponding to $(h0l)$ in the case of an orthorhombic crystal appears to “split” along \vec{Q}_z into two spots corresponding to the two rotated domains. The angle between either of these spots and the horizontal can be used to determine the monoclinic tilt, which we find to be $\beta = 85.95^\circ$.

Observed extinction conditions (Figure S3) imply an A -centered monoclinic cell and are consistent with three possible space groups (No. 12 $A2/m$, No. 5 $A2$, No. 8 Am).³⁸ In Figure 1e we present a pair of scanning transmission electron microscopy (STEM) images labeled by the zone axis of the crystalline material. An extended set of micrographs is presented in the Supporting Information, showing that domains occur in varying proportions randomly in the sample, consistent with the X-ray data. Energy dispersive X-ray spectroscopy taken in the TEM (Figure S10) confirms the

1:2 La:Sb stoichiometry within an accepted tolerance of $\approx 10\%$ for EDX in STEM.^{39,40} Line cuts along Sb layers (Figure S11) reveal that Sb sheets form planar layers in contrast to the puckered layers found in the YbSb₂ structure.²⁰ Our proposed crystal structure was obtained from density functional theory calculations, to be discussed in the next section. In Figure 1e we overlay the calculated structure on the TEM images with lattice parameters taken from experiment, confirming the proposed atomic arrangements. The space group for the LaSb₂ films was determined to be No. 12 *A2/m*.

The stacking arrangements for these materials can be constructed from QL building blocks as shown in Figure 1a, where the upper block is shifted relative to the lower one by a displacement vector $\vec{d} = (d_x a_0, d_y b_0)$. This construction is possible because of the relatively weak bond between neighboring La–Sb layers, substantiated by the lower cleavage energy (Figure S4) and the longer interblock La–Sb bond length (>3.5 Å) compared to those of the intrablock bonds. The energy landscape of the two LaSb₂ building blocks on the two-dimensional (d_x, d_y) displacement space is shown in Figure 2a. This is obtained using a relaxed unit block slab where $a_0 = b_0 = 4.50$ Å are the calculated equilibrium in-plane lattice constants, and shifting it relative to an adjacent slab, with subsequent relaxation of the atomic positions. The calculations reveal (i) four global energy minima, Y^\pm , and (ii) six saddle points, Y^0 and S^\pm . We note that the energy map preserves the C_4 rotational symmetry, inherited from the building block ($a_0 = b_0$). It is evident that the vertical stacking (d_x, d_y) = (0, 0) is not favored. The S^\pm sites, (d_x, d_y) = ($\pm 0.25, \pm 0.25$), correspond to the displacement of the Sm-type LaSb₂ structure (space group No. 64, *Cmca*) consisting of building blocks with a stacking sequence of $\cdots S^+ S^- S^+ S^- \cdots$ (see also Table 1). The Yb-type structure (space group No. 63, *Cmcm*) can also be explained with the stacking sequences of $\cdots Y^0 Y^0 Y^0 Y^0 \cdots$. The two displacements between three consecutive building blocks are illustrated in Figure 2b and c for the Sm- and Yb-type structures, where the successive lateral displacements are compensated and both Sm- and Yb-type structures preserve orthorhombicity. The tetragonal symmetry is broken in Sm- and Yb-type LaSb₂ due to the displacement of stacking sites that breaks the C_4 symmetry of the building block. Both phases, however, do not contain the lowest energy stacking arrangement Y^\pm according to these calculations. Figure 2d shows one potential structure with repeating Y^+ stacking, $\cdots Y^+ Y^+ Y^+ Y^+ \cdots$, where the noncompensating displacement along the \hat{x} direction leads to shear deformation of the out-of-plane lattice vector, rendering the system monoclinic. To further validate this method, we also have applied it to the SmSb₂ and YbSb₂ structures and have found the expected stacking arrangements are reproduced (Figure S5).

Table 1 lists the calculated relative total energies of the different stacking sequences, as well as experimentally obtained values for bulk crystals¹⁶ and our thin films. The calculations point to the monoclinic structure (Yb-mono) as the ground state, with the previously synthesized Sm-type or proposed Yb-type phases exhibiting higher total energies. We note, however, that this is the energy at $T = 0$ and therefore is distinct from the free energy at elevated temperatures which contains phononic, magnetic, and electronic entropic contributions. The novel Yb-mono phase is consistent with the MBE-grown LaSb₂ structure where all the calculated lattice constants and monoclinic angle β agree well with the diffraction data within an error of 1%. Combining diffraction, calculation, and

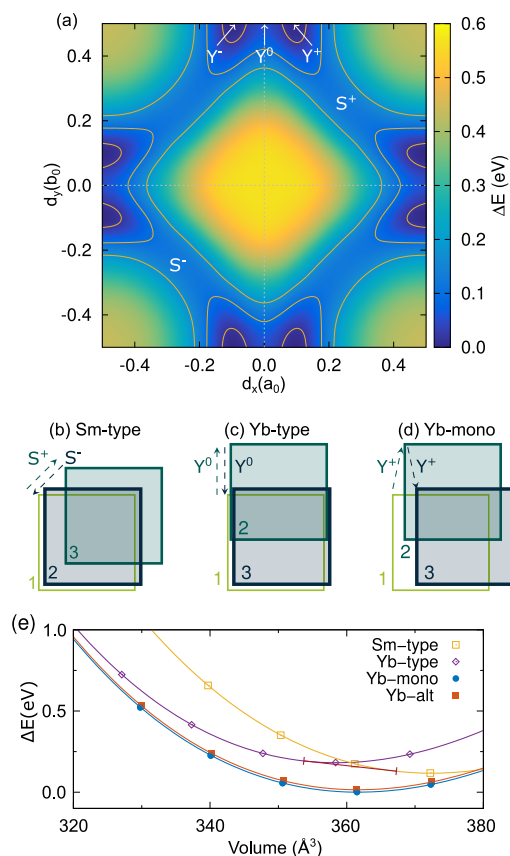


Figure 2. (a) Energy landscape of sliding two LaSb₂ QL building blocks in Figure 1a on the two-dimensional (d_x, d_y) displacement space. The global energy minima are denoted by Y^\pm and the saddle points by S^\pm and Y^0 . (b–d) Schematic top view of three LaSb₂ building blocks with different stacking sequences. The cell with label 1 denotes the bottom block. (b) Sm-type orthorhombic structure with alternating stacking sites of $[S^+ S^-]$; (c) Yb-type orthorhombic structure with a sole stacking site of $[Y^0]$; and (d) Yb-like monoclinic structure with a sole stacking site of $[Y^+]$ resulting in a tilted out-of-plane lattice vector. (e) Total energies versus volume for the four crystal structures, where the solid curves are fits to the Birch–Murnaghan equation of state.

microscopy results, we unambiguously confirm the novel Yb-mono polymorph has been stabilized.

The calculations also reveal a new orthorhombic phase (Yb-alt in Table 1, space group No. 58, *Pnnm*) with alternating stacking sequences of $\cdots Y^+ Y^- Y^+ Y^- \cdots$, which is close in energy to the ground state Yb-mono structure. In order to study the relative stability of the four crystal structures under hydrostatic pressure, we show in Figure 2e the calculated total energies as a function of volume. We find that the Yb-mono structure remains the ground state under hydrostatic pressure, which on the other hand induces a structural phase transition from the Sm-type to the Yb-type structures at 0.749 GPa, close to the calculated value in ref 15 of ≈ 0.5 GPa.

In Figure 3a we present temperature dependence of resistivity for a film of thickness $t = 144$ nm. The films show metallic $\rho(T)$ with an RRR ($R_{300\text{ K}}/R_{2.5\text{ K}}$) of 26. No features with sharp changes in $d\rho/dT$ are observed up to $T = 400$ K, which would indicate the presence of a CDW transition or first-order structural transition. In Figure 3b and 3d, the symmetrized magnetoresistance (MR) and antisymmetrized Hall resistivity up to fields of $B = 9$ T for several temperatures

Table 1. Calculated Relative Total Energies, Lattice Constants, and Angles of Several LaSb₂ Bulk Phases Corresponding to Different Stacking Sequences^a

system	stacking sequence	SG	ΔE (meV/La)	a (Å)	b (Å)	c (Å)	α (deg)	β (deg)	γ (deg)
Sm-type	...S ⁺ S ⁻ S ⁺ S ⁻ [S ⁺ S ⁻]...	64	29	4.470	4.470	18.628	90.0	90.0	91.1
Yb-type	...Y ⁰ Y ⁰ Y ⁰ Y ⁰ [Y ⁰]...	63	45	4.477	4.546	17.607	90.0	90.0	90.0
Yb-alt	...Y ⁺ Y ⁻ Y ⁺ Y ⁻ [Y ⁺ Y ⁻]...	58	4	4.555	4.480	17.717	90.0	90.0	90.0
Yb-mono	...Y ⁺ Y ⁺ Y ⁺ Y ⁺ [Y ⁺]...	12	0	4.562	4.483	17.711	90.0	86.3	90.0
bulk exp.		64		4.42	4.42	18.56	90.0	90.0	91.2
this work		12		4.52	4.43	17.62	90.0	85.96	90.0

^aSG indicates the space group. The Sm-type structure is a base-centered orthorhombic cell, and the lattice constants, a and b , are equivalent to the distance from the corner to the center of the conventional cell base.

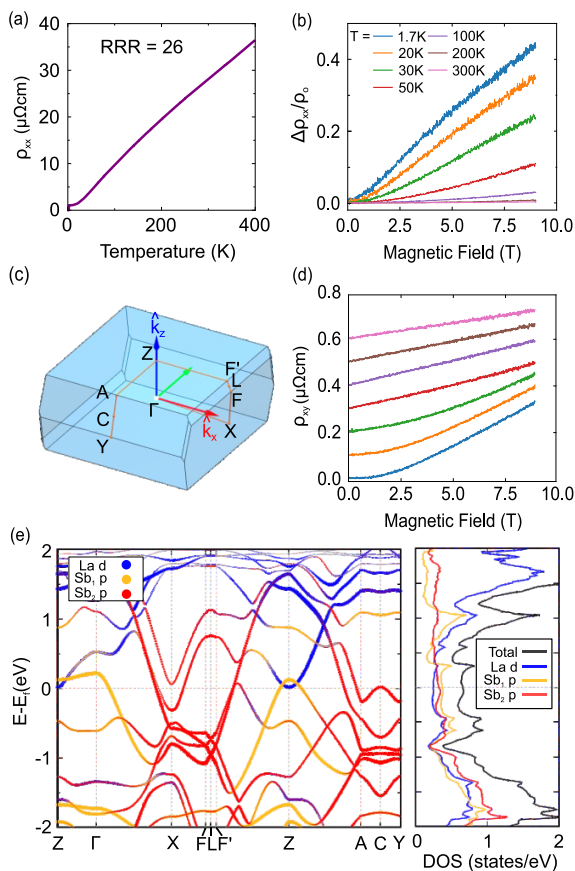


Figure 3. (a) Temperature-dependent longitudinal resistance. (b) Longitudinal magnetoresistance at different temperatures. (c) Brillouin zone and relevant high-symmetry points of the monoclinic structure. (d) Hall resistance curves at different temperatures, offset for clarity. (e) Calculated band structure with color-coded dispersion features associated with projections on various atomic sites, along with the corresponding DOS (total DOS scaled by $\frac{1}{4}$).

are given. The curvature of the Hall resistance indicates multiple carrier types while the MR displays linear behavior at high fields at low temperature, similar to bulk crystal data both in ambient conditions and under applied pressure, albeit with a reduced magnitude compared to bulk crystals.^{22,25} Two carrier Drude fits⁴¹ were applied to the MR data but were not found to capture the behavior at low temperature (Figure S7).

In Figure 3c we plot the Brillouin zone of the monoclinic crystal structure with the relevant high-symmetry points. The band structure along the high-symmetry directions (orange path in (c)) and the corresponding orbital-projected density of states (DOS) are displayed in Figure 3e, where the blue,

orange, and red colors denote projections on the La-5d, Sb₁/5p, and Sb₂/5p orbitals (Sb₁ are on the La/Sb corrugated layer and Sb₂ are on the 2D Sb sheets in Figure 1a). The highly dispersing Sb₁/5p and Sb₂/5p bands crossing the Fermi level along the Γ -X and Γ -Z directions indicate high carrier mobility along the in-plane directions similar to those in the bulk orthorhombic LaSb₂ structure^{28,42,43} and in other topological square-net materials.³ The presence of both hole-like and electron-like pockets at the Fermi level is in agreement with the observation of multiple carrier types from the Hall measurements.

In Figure 4a we present data showing the presence of a sharp superconducting transition with resistive $T_c \approx 2.05$ K. The

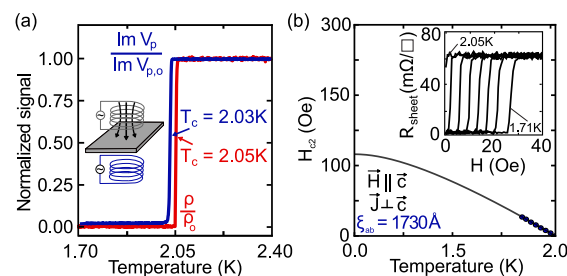


Figure 4. (a) Superconductivity measured in a 144 nm film via resistance (red) and mutual inductance (blue) methods. (b) Critical field as a function of temperature with WHH fit to extrapolate to zero temperature. Inset: a subset of critical field isotherms, taken approximately every 50 mK, between 2.05 K and 1.71 K.

films display zero resistance and flux expulsion, as evidenced by a drop in voltage on the secondary coil in a mutual inductance experimental geometry (inset of 4a). The measured T_c in the two experiments agree within 1%. In 4b, we plot the perpendicular critical field as a function of temperature. Determination of H_{c2} was performed by fitting the resistive transition isotherms to a sigmoid function $\rho = \frac{\rho_0}{1 + \exp(-k(H - H_{c2}))}$ (see Methods). Data were taken every 25 mK between 2.05 and 1.71 K. The full set of critical field isotherms and fits is given in Figure S12. We extrapolate to zero temperature by fitting the data using the single-band, Werthamer, Helfand, and Hohenberg (WHH) formula⁴⁴ in the limit where orbital pair-breaking effects dominate spin paramagnetic and spin-orbit effects. We use the extrapolated value for $H_{c2\perp}(0) \approx 110$ Oe to estimate the coherence length, which gives $\xi_{ab} = \sqrt{\frac{\Phi_0}{2\pi H_{c2\perp}(0)}} = 1730$ Å. For comparison, a single-band Ginzburg-Landau model⁴⁵ gives $\xi_{ab} = 1400$ Å. These values are in agreement with the findings in bulk crystals under pressure.³⁰ The inset of 4b displays a subset of the

isotherms used in the fitting and further demonstrates the sharpness of the transition.

One possibility for the stabilization of the monoclinic LaSb₂ is related to epitaxial strain or other perturbations induced by the substrate. The square symmetry of the MgO substrate would tend to favor layers with reduced orthorhombicity and lattice mismatch with the substrate. In the monoclinic phase, the *a*- and *b*-axes differ by $\approx 2\%$ compared to approximately $\approx 2.5\%$ for the ambient phase structure. However, the large lattice mismatch of $\approx 6\%$ for the monoclinic structure makes it unlikely that coherent strain persists in the epilayer beyond the first 1–2 QL and therefore unlikely that the monoclinic structure is stabilized by epitaxial strain. Another possibility for the observation of the monoclinic phase in thin films, yet not in the bulk crystals, is the lower growth temperature used in the MBE growth processes ($\approx 500\text{ }^{\circ}\text{C} < T_{\text{melt}} = 630\text{ }^{\circ}\text{C}$).⁴⁶ During flux growth, crystals are obtained by slowly cooling the melt from the liquidus temperature ($\approx 1000\text{ }^{\circ}\text{C}$), over a period of tens of hours and decanting the liquid flux slightly above the solidification temperature of the desired phase.²³ Given the results of the 0 K DFT simulations, monoclinic LaSb₂ may therefore be a low-temperature crystalline phase that would be preferentially stabilized by the vapor–solid reaction of MBE.

As of the time of writing, no single-crystal diffraction data have been reported for bulk-LaSb₂ at high *P*. The scarcity of crystals makes such experiments challenging. Previous studies¹⁵ have proposed YbSb₂ as a candidate structure for the high-*P* phase on the basis of DFT calculations. Our calculations agree that while the YbSb₂ structure is more stable compared to the SmSb₂ structure under pressure, the monoclinic Y⁺ structure is the ground state. We propose that the application of pressure results in a structural transition to either the Y⁺ polymorph or similar orthorhombic structure labeled [Y⁺Y[−]], which is nearly degenerate. The association of the Y⁺ phase with the high-pressure phase of the bulk crystal is further bolstered by the absence of resistance anomalies at high temperature and a sharp superconducting transition at 2 K. In bulk LaSb₂, the superconducting transition is broad, with onset temperatures of about $T = 2\text{ K}$, yet only reaching a fully superconducting state at $T = 0.4\text{--}0.5\text{ K}$.³⁰ Scanning tunneling microscopy experiments have suggested that the superconductivity is more robust at the surface with a measured T_c of 1.2 K.⁴⁷ The transition sharpens with *P* with concomitant suppression of the high-temperature resistance anomaly.^{15,29} A maximum $T_c \approx 2\text{ K}$ was observed under applied pressure of 4.5 kbar, at which point the anomaly is completely absent.^{15,30} While the presence of a CDW transition in bulk LaSb₂ remains an open question⁴⁸ with recent studies⁴⁹ having found no evidence of a CDW gap opening, the strongly 2D-like Fermi surface in the other square-net systems such as SmSb₂-type LaSb₂ is not present in our structure (Figure S8 for discussion), which may play a role in the suppression of the resistance anomaly associated with a structural transition that competes with superconductivity. Further investigations into the superconducting phase will form the basis of future studies.

In summary, we have experimentally and theoretically presented a newly stable polymorph in the family of rare-earth dantimonides in thin films of LaSb₂ deposited on MgO (001). The films are superconducting with a critical temperature enhanced relative to reports on bulk crystals under ambient conditions. This study points toward this family of materials as a promising platform to study superconductivity

with varying lattice motifs and layering orders that may be inaccessible or difficult to characterize in bulk samples.

■ ASSOCIATED CONTENT

Data Availability Statement

The data that support the findings of this study are available from the corresponding author upon reasonable request.

Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acs.nanolett.4c01068>.

Additional text including experimental sections on molecular beam epitaxy, X-ray diffraction, transmission electron microscopy, first-principles calculations, transport measurements, and mutual inductance measurements; additional figures of RHEED data for growth, rocking curve and ϕ -scan of films, additional reciprocal space maps of films, calculated cleavage energy of films, comparison of stacking for SmSb₂ and YbSb₂, wide range resistance scans of films, temperature-dependent magnetotransport, calculated Fermi surfaces, wide-area TEM image, elemental mapping of films, line profiles of TEM data, temperature dependence of the superconducting transition (PDF)

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Notes

The authors declare no competing financial interest.

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